

/ Descriptions

TO-126(R) NPN Silicon NPN transistor in a TO-126(R) Plastic Package.

/ Features

High voltage.

/ Applications

High voltage switching and humidifier.

/ Equivalent Circuit



/ Pinning



PIN1 Base PIN 2 Collector PIN 3 Emitter

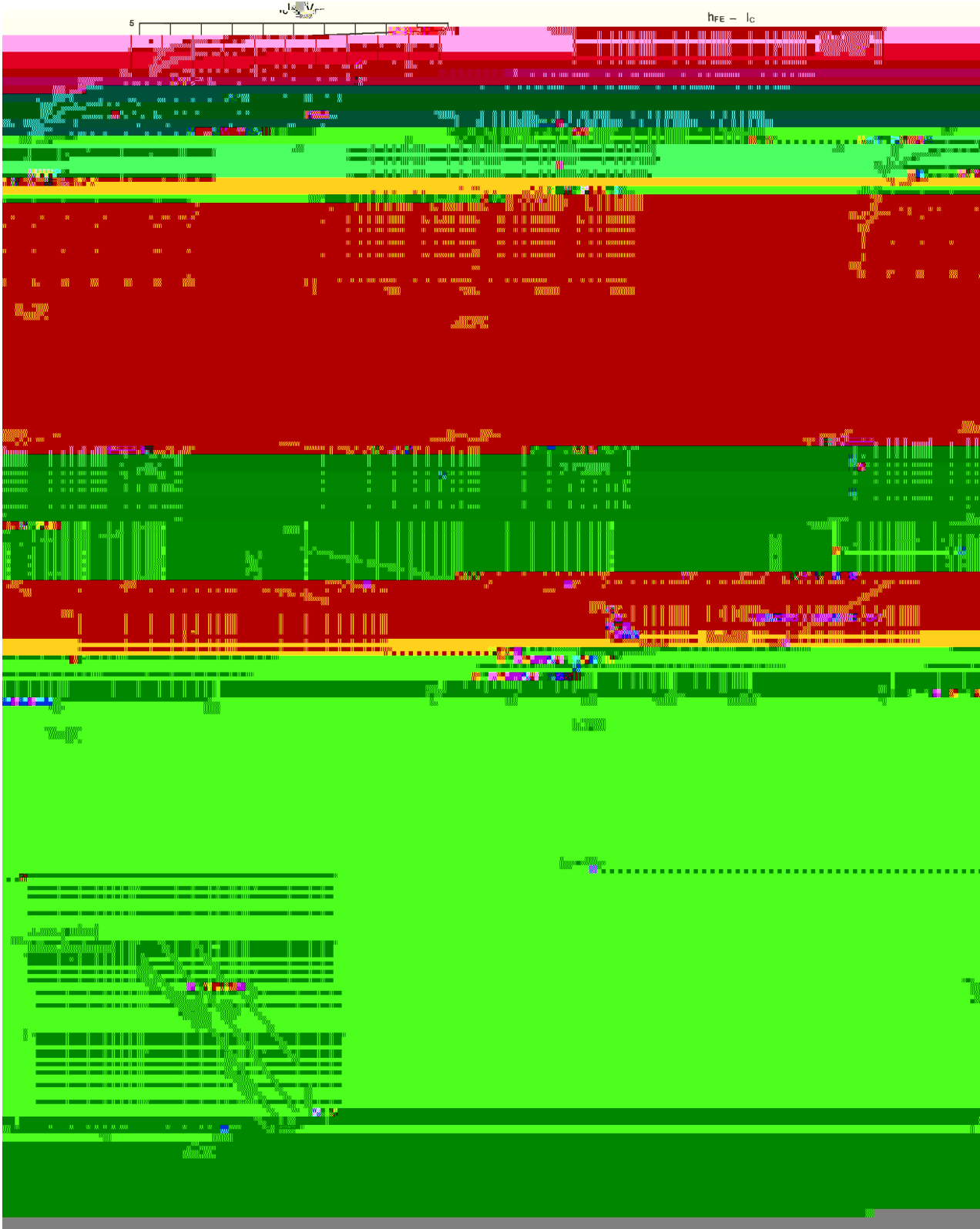
/ h_{FE} Classifications & Marking

See Marking Instructions.

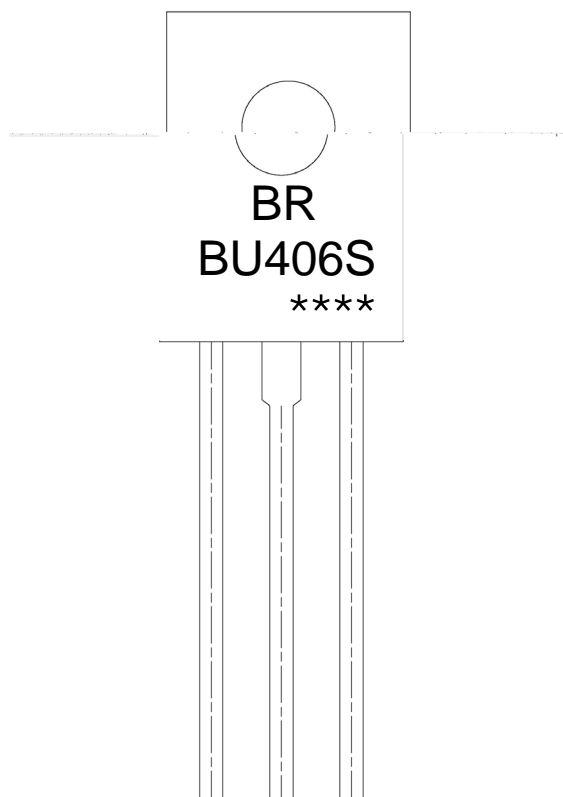
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	200	V
Collector to Emitter Voltage	V_{CEO}	120	V
Emitter to Base Voltage	V_{EBO}	6.0	V
Collector Current - Continuous	I_C	7.0	A
Peak Collector Current	I_{Cp}	10	A
Base Current	I_B	2.0	A
Collector Power Dissipation	P_C	1.5	W
Collector Power Dissipation	$P_C(T_C=25^\circ C)$	20	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-Off Current	$I_{CES(1)}$	$V_{CE}=V_{BE}$ $V_{BE}=0$			100	A
	$I_{CES(2)}$	$V_{CE}=V_{BE}$ $V_{BE}=0$			50	A
	$I_{CES(3)}$	$V_{CE}=150V$ T $V_{BE}=0$				

/ Electrical Characteristic Curve



/ Marking Instructions



BR

BU 406S

Note:

BR: Company Code

BU406S: Product Type.

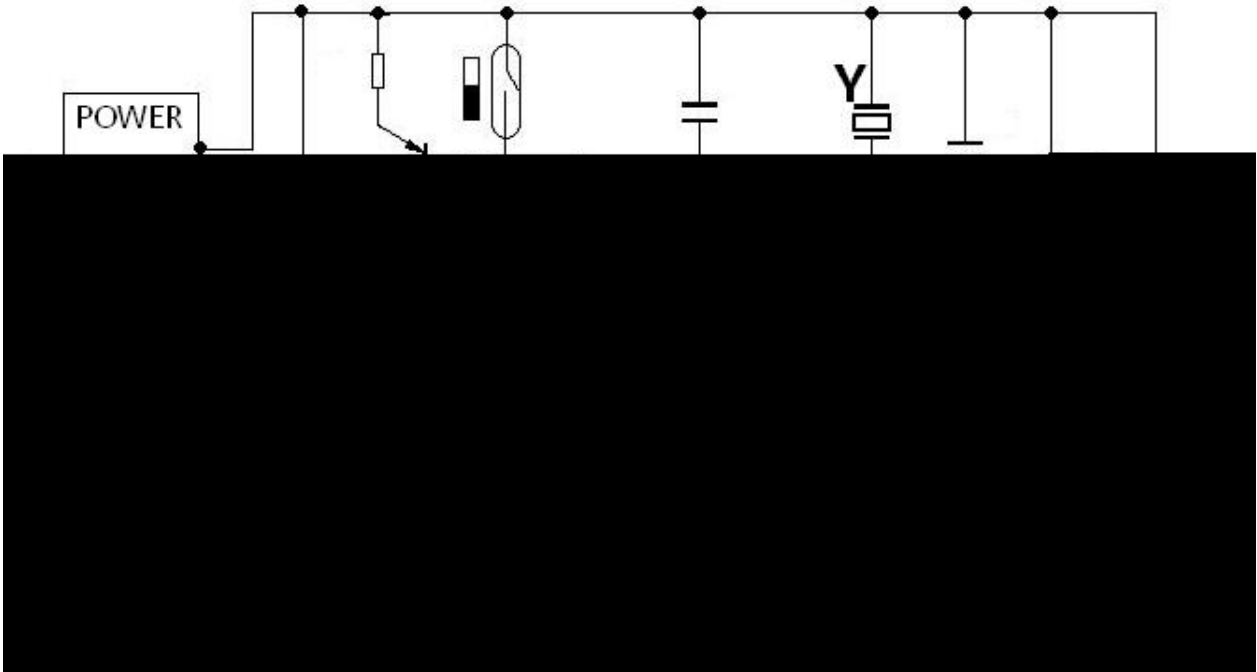
****: Lot No. Code, code change with Lot No.

BU406SL
Rev.F Mar.-2016

(

/ Notices

3MHZ



- 1 3.0MHZ
- 2 40V
- 3 45W
- 4 HFE 60-70,70-80,80-90

- 1 HFE HFE 60-70 70-80 80-90
- 2 HFE

- 1 Y
- 2

- 3
- 3.1
- 3.2 5kgf.cm
- 3.3 PCB
- 3.4
- 3.5